

# Cláudia Gonçalves Rodrigues

## List of Publications by Year in descending order

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Version: 2024-02-01

57  
papers

433  
citations

566801

15  
h-index

839053

18  
g-index

57  
all docs

57  
docs citations

57  
times ranked

108  
citing authors

| #  | ARTICLE  | IF  | CITATIONS |
|----|--|-----|-----------|
| 1  | Experimentos práticos e didáticos de baixo custo para o ensino de Óptica: reflexo, refração e espelhos planos. <i>Conjeturas</i> , 2022, 22, 916-935.  | 0.0 | 0         |
| 2  | Atividades experimentais de baixo custo para o ensino de mecânica. , 2022, 22, 909-932.  |     | 0         |
| 3  | Nonlinear charge transport in highly polar semiconductors: GaN, AlN, InN and GaAs. <i>Pramana - Journal of Physics</i> , 2021, 95, 1.  | 0.9 | 3         |
| 4  | Hot carrier dynamics of photoinjected plasma in indium nitride. <i>European Physical Journal B</i> , 2021, 94, 1.  | 0.6 | 1         |
| 5  | Nonlinear higher-order hydrodynamics: Fluids under driven flow and shear pressure. <i>Physics of Fluids</i> , 2021, 33, 067111.  | 1.6 | 4         |
| 6  | Ultrafast dynamics of carriers and phonons of photoinjected double-plasma in aluminium nitride. <i>Revista Mexicana De Física</i> , 2021, 67, 318-323.   | 0.2 | 2         |
| 7  | Extended Navier-Stokes Equations in the Framework of Higher-Order Generalized Hydrodynamics. <i>Brazilian Journal of Physics</i> , 2021, 51, 1904-1915.  | 0.7 | 0         |
| 8  | Panorama do mercado global da indústria de semicondutores / Overview of the global semiconductor industry market. <i>Brazilian Journal of Development</i> , 2021, 7, 74936-74944.                  | 0.0 | 0         |
| 9  | Electron Mobility in Bulk n-Doped SiC-Polytypes 3C-SiC, 4H-SiC, and 6H-SiC: A Comparison. <i>Semiconductors</i> , 2021, 55, 625-632.   | 0.2 | 2         |
| 10 | Glucose is an active chemical agent on degradation of hydroxyapatite nanostructure. <i>Materials Chemistry and Physics</i> , 2020, 240, 122166.  | 2.0 | 10        |
| 11 | Anisotropic Carrier Transport in n-Doped 6H-SiC. <i>Physics of the Solid State</i> , 2020, 62, 110-115.  | 0.2 | 4         |
| 12 | Immobilization of Paclitaxel on Hydroxyapatite for Breast Cancer Investigations. <i>Langmuir</i> , 2020, 36, 8723-8732.  | 1.6 | 6         |
| 13 | TRANSPORTE DE CARGA ELÉTRICA NO SEMICONDUTOR 4H-SiC DOPADO TIPO p. <i>Interfaces Científicas - Exatas E Tecnológicas</i> , 2020, 4, 144-159.   | 0.0 | 1         |
| 14 | Anisotropic hole drift velocity in 4H-SiC. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , 2019, 249, 114426.  | 1.7 | 3         |
| 15 | Statistical Mesoscopic Hydro-thermodynamics: the Description of Kinetics and Hydrodynamics of Nonequilibrium Processes in Single Liquids. <i>Brazilian Journal of Physics</i> , 2019, 49, 277-287. | 0.7 | 4         |
| 16 | Study of Electron Transport in 4H-SiC by Using Nonequilibrium Statistical Ensemble Formalism. <i>Brazilian Journal of Physics</i> , 2019, 49, 494-501.   | 0.7 | 2         |
| 17 | Caracterização do transporte de portadores de carga no semicondutor Sulfeto de Zinco (ZnS) dopado tipo n. <i>Revista Tecnológica</i> , 2019, 28, 39-50.  | 0.1 | 0         |
| 18 | Electron transport in bulk n-doped 3C-SiC by using a non-equilibrium quantum kinetic theory. <i>European Physical Journal B</i> , 2019, 92, 1.   | 0.6 | 4         |

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|----|---|-----|-----------|
| 19 | Estudo do Transporte Eletrônico no Semicondutor Arseneto de Gálio Usando a Equação de Newton-Langevin. Revista Arithmã³s, 2019, 1, 47.  | 0.0 | 0         |
| 20 | The calculated low-energy side of the luminescence spectrum in zinc selenide. Journal of Luminescence, 2018, 199, 450-453.  | 1.5 | 4         |
| 21 | Statistical Irreversible Thermodynamics in the Framework of Zubarev's Nonequilibrium Statistical Operator Method. Theoretical and Mathematical Physics(Russian Federation), 2018, 194, 4-29.          | 0.3 | 18        |
| 22 | Non-equilibrium Bose-Einstein-Like Condensation. Advanced Quantum Technologies, 2018, 1, 1800023.   | 1.8 | 7         |
| 23 | Maxwell times in higher-order generalized hydrodynamics: Classical fluids, and carriers and phonons in semiconductors. Physical Review E, 2017, 95, 022104.   | 0.8 | 6         |
| 24 | Ultrafast Transport Transient in n-Doped ZnS in Wurtzite and Zincblende Phases. Condensed Matter, 2017, 2, 12.  | 0.8 | 2         |
| 25 | Interatomic correlations moments of atoms in the two-dimensional hexagonal lattice by using Morse and Lenard-Jones potentials. Physica B: Condensed Matter, 2016, 490, 46-48.                         | 1.3 | 1         |
| 26 | Higher-order generalized hydrodynamics of carriers and phonons in semiconductors in the presence of electric fields: Macro to nano. Physica Status Solidi (B): Basic Research, 2015, 252, 2802-2819.  | 0.7 | 9         |
| 27 | Topics in Present-day Science Technology and Innovation: Ultrafast Relaxation Processes in Semiconductors. Materials Research, 2015, 18, 453-467.   | 0.6 | 4         |
| 28 | Response Function Theory for Many-Body Systems Away from Equilibrium: Conditions of Ultrafast-Time and Ultrasmall-Space Experimental Resolution. Brazilian Journal of Physics, 2015, 45, 166-193.     | 0.7 | 2         |
| 29 | Higher-order generalized hydrodynamics: Foundations within a nonequilibrium statistical ensemble formalism. Physical Review E, 2015, 91, 063011.  | 0.8 | 12        |
| 30 | Complexidade, auto-organizaçã³o e informaçã³o em sistemas dinãmicos. Revista Brasileira De Ensino De Fisica, 2015, 37, 2314-1-2314-30.  | 0.2 | 1         |
| 31 | Thermal conductivity in higher-order generalized hydrodynamics: Characterization of nanowires of silicon and gallium nitride. Physica E: Low-Dimensional Systems and Nanostructures, 2014, 60, 50-58. | 1.3 | 14        |
| 32 | Mesoscopic hydro-thermodynamics of phonons in semiconductors: heat transport in III-nitrides. European Physical Journal B, 2013, 86, 1.   | 0.6 | 18        |
| 33 | Drifting electron excitation of acoustic phonons: Cerenkov-like effect in n-GaN. Journal of Applied Physics, 2013, 113, 113701.   | 1.1 | 17        |
| 34 | Onset for the Electron Velocity Overshoot in Indium Nitride. Chinese Physics Letters, 2012, 29, 127201.   | 1.3 | 2         |
| 35 | Nonlinear electronic transport behavior in Indium Nitride. Materials Chemistry and Physics, 2012, 137, 317-322.   | 2.0 | 5         |
| 36 | The role of nonequilibrium thermo-mechanical statistics in modern technologies and industrial processes: an overview. Brazilian Journal of Physics, 2010, 40, 63-91.                                  | 0.7 | 18        |

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|----|--|-----|-----------|
| 37 | Evolution kinetics of nonequilibrium longitudinal-optical phonons generated by drifting electrons in III-nitrides: longitudinal-optical-phonon resonance. <i>Journal of Applied Physics</i> , 2010, 108, 033716. | 1.1 | 20        |
| 38 | Theoretical calculations of nonlinear electronic transport behavior in III-nitrides: GaN and AlN. <i>Physica Status Solidi (B): Basic Research</i> , 2009, 246, 417-425.   | 0.7 | 9         |
| 39 | Transient transport in III-nitrides: interplay of momentum and energy relaxation times. <i>Journal of Physics Condensed Matter</i> , 2007, 19, 346214.   | 0.7 | 14        |
| 40 | Nonlinear hole transport and nonequilibrium thermodynamics in group III-nitrides under the influence of electric fields. <i>Journal of Applied Physics</i> , 2007, 102, 073714.                                  | 1.1 | 17        |
| 41 | Hot-carrier relaxation in photoinjected ZnSe. <i>Microelectronics Journal</i> , 2007, 38, 24-26.   | 1.1 | 5         |
| 42 | Electron transport in GaN(ZB) and AlN(WZ). <i>Journal of Materials Science</i> , 2007, 42, 396-400.  | 1.7 | 5         |
| 43 | Nonlinear charge transport in III-N semiconductors: Mobility, diffusion, and a generalized Einstein relation. <i>Journal of Applied Physics</i> , 2006, 99, 073701.  | 1.1 | 21        |
| 44 | Non-Linear electron mobility in n-doped III-Nitrides. <i>Brazilian Journal of Physics</i> , 2006, 36, 255.   | 0.7 | 19        |
| 45 | Electron mobility in n-doped zinc sulphide. <i>Microelectronics Journal</i> , 2006, 37, 657-660.   | 1.1 | 15        |
| 46 | Nonlinear transport in n-III-nitrides: Selective amplification and emission of coherent LO phonons. <i>Solid State Communications</i> , 2006, 140, 135-140.  | 0.9 | 21        |
| 47 | Ultrafast relaxation kinetics of photoinjected plasma in III-nitrides. <i>Journal Physics D: Applied Physics</i> , 2005, 38, 3584-3589.  | 1.3 | 18        |
| 48 | Nonlinear transport properties of doped III-N and GaAs polar semiconductors: A comparison. <i>Journal of Applied Physics</i> , 2005, 98, 043703.   | 1.1 | 19        |
| 49 | Nonlinear transport properties of III-nitrides in electric field. <i>Journal of Applied Physics</i> , 2005, 98, 043702.  | 1.1 | 24        |
| 50 | The Melting Curve of Argon by Using Lindemann's Criterion. <i>European Physical Journal D</i> , 2004, 54, 849-856.   | 0.4 | 0         |
| 51 | Electron mobility in nitride materials. <i>Brazilian Journal of Physics</i> , 2002, 32, 439-441.   | 0.7 | 17        |
| 52 | Urbach's tail in III-nitrides under an electric field. <i>Journal of Applied Physics</i> , 2001, 90, 1879-1882.  | 1.1 | 20        |
| 53 | Comparação entre as Ementas de um Curso de Mecânica Quântica e Física Moderna. <i>Revista Brasileira De Ensino De Física</i> , 2001, 23, 360-365.  | 0.2 | 0         |
| 54 | Nonequilibrium ensemble derivation of hydrodynamic heat transport and higher-order generalizations. <i>Indian Journal of Physics</i> , 0, , 1.   | 0.9 | 1         |

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|----|---|-----|-----------|
| 55 | Sobre modelagem matemática e formalismos estatísticos de sistemas complexos. Revista Brasileira De Ensino De Fisica, 0, 42, . | 0.2 | 1         |
| 56 | A função relativística de distribuição de velocidades de Maxwell-Jüttner. Revista Brasileira De Ensino De Fisica, 0, 44, .    | 0.2 | 1         |
| 57 | Transporte Eletrônico no Semicondutor Carbetto de Silício na Fase 3C. , 0, 8, .   |     | 0         |